

CMOS LOGIC INTERFACE.

- Isolation Voltage : 2500V_{rms} (Min.)
- Current Transfer Ratio
 : 6N138 - 300% (Min.) (I_F=1.6mA)
 : 6N139 - 400% (Min.) (I_F=0.5mA)
- Switching Time: 6N138 - t_{PHL}=10μs (Max.)
 - t_{PLH}=35μs (Max.)
 6N139 - t_{PHL}=1μs (Max.)
 - t_{PLH}=7μs (Max.)
- UL Recognized : UL1577, File No. E67349

Weight : 0.54g

1 : N.C.
2 : ANODE
3 : CATHODE
4 : N.C.
5 : GND
6 : OUTPUT
7 : OUTPUT BASE
8 : V_{CC}

● TOSHIBA is continually working to improve the quality and the reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to observe standards of safety, and to avoid situations in which a malfunction or failure of a TOSHIBA product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent products specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.

MAXIMUM RATINGS (*) (Ta = 0°C to +70°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
LED	Forward Current (Note 1)	I _F	20	mA
	Pulse Forward Current	I _{FP} (*)	40	mA
	Total Pulse Forward Current	I _{FP} (*)	1	A
	Reverse Voltage	V _R	5	V
	Diode Power Dissipation (Note 2)	P _D	35	mW
DETECTOR	Output Current (Note 3)	I _O	60	mA
	Emitter-Base Reverse Voltage	V _{EB}	0.5	V
	Supply Voltage	V _{CC} (*)	−0.5 to 18	V
	Output Voltage	V _O (*)	−0.5 to 18	V
	Output Power Dissipation (Note 4)	P _O	100	mW
Operating Temperature Range		T _{opr}	0 to 70	°C
Storage Temperature Range		T _{stg}	−55 to 125	°C
Lead Solder Temperature (10s) (*)		T _{sol}	260	°C
Isolation Voltage (1min., R.H. ≤ 60%)		BV _S (**)	2500	V _{rms}
			3540	V _{dc}

(*) JEDEC Registered Data

(**) Not Registered JEDEC

(*) 50% duty cycle, 1ms pulse width

(*) Pulse width 1μs, 300pps

(*) 6N138... −0.5 to 7V

(*) 1.6mm below seating plane

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- Gallium arsenide (GaAs) is a substance used in the products described in this document. GaAs dust and fumes are toxic. Do not break, cut or pulverize the product, or use chemicals to dissolve them. When disposing of the products, follow the appropriate regulations. Do not dispose of the products with other industrial waste or with domestic garbage.
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ELECTRICAL CHARACTERISTICS

OVER RECOMMENDED TEMPERATURE (Ta=0°C to 70°C, Unless otherwise noted)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	(*)TYP.	MAX.	UNIT
Current Transfer Ratio (Note 5, 6)	6N139	CTR (*)	$I_F = 0.5\text{mA}$, $V_O = 0.4\text{V}$ $V_{CC} = 4.5\text{V}$	400	800	—	%
			$I_F = 1.6\text{mA}$, $V_O = 0.4\text{V}$ $V_{CC} = 4.5\text{V}$	500	900	—	
	6N138			300	600	—	
Logic Low Output Voltage (Note 6)	6N139	V_{OL}	$I_F = 1.6\text{mA}$, $I_O = 6.4\text{mA}$ $V_{CC} = 4.5\text{V}$	—	0.1	0.4	V
			$I_F = 5\text{mA}$, $I_O = 15\text{mA}$ $V_{CC} = 4.5\text{V}$	—	0.1	0.4	
			$I_F = 12\text{mA}$, $I_O = 24\text{mA}$ $V_{CC} = 4.5\text{V}$	—	0.2	0.4	
	6N138		$I_F = 1.6\text{mA}$, $I_O = 4.8\text{mA}$ $V_{CC} = 4.5\text{V}$	—	0.1	0.4	
Logic High Output Current (Note 6)	6N139	I_{OH} (*)	$I_F = 0\text{mA}$, $V_O = V_{CC} = 18\text{V}$	—	0.05	100	μA
	6N138		$I_F = 0\text{mA}$, $V_O = V_{CC} = 7\text{V}$	—	0.05	250	
Logic Low Supply Current (Note 6)		I_{CCL}	$I_F = 1.6\text{mA}$, $V_O = \text{Open}$ $V_{CC} = 5\text{V}$	—	0.2	—	mA
Logic High Supply Current (Note 6)		I_{CCH}	$I_F = 0\text{mA}$, $V_O = \text{Open}$, $V_{CC} = 5\text{V}$	—	10	—	nA
Input Forward Voltage		V_F (*)	$I_F = 1.6\text{mA}$, $T_a = 25^\circ\text{C}$	—	1.65	1.7	V
Input Reverse Breakdown Voltage		BV_R (*)	$I_R = 10\mu\text{A}$, $T_a = 25^\circ\text{C}$	5	—	—	V
Temperature Coefficient of Forward Voltage		$\Delta V_F / \Delta T_a$	$I_F = 1.6\text{mA}$	—	−1.9	—	mV / °C
Input Capacitance		C_{IN}	$f = 1\text{MHz}$, $V_F = 0$	—	60	—	pF
Resistance (Input-Output)		R_{I-O}	$V_{I-O} = 500\text{V}$ (Note 7), $R.H. \leq 60\%$	—	10^{12}	—	Ω
Capacitance (Input-Output)		C_{I-O}	$f = 1\text{MHz}$ (Note 7)	—	0.6	—	pF

(**) JEDEC Registered Data.

(*) All typicals at $T_a = 25^\circ\text{C}$ and $V_{CC} = 5\text{V}$, Unless otherwise noted.

SWITCHING SPECIFICATIONS ($T_a = 25^\circ\text{C}$, $V_{CC} = 5\text{V}$, unless otherwise specified)

CHARACTERISTIC		SYMBOL	TEST CIRCUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Propagation Delay Time to Logic Low at Output (Note 6, 8)	6N139	t_{pHL} (*)	1	$I_F=0.5\text{mA}$, $R_L=4.7\text{k}\Omega$	—	5	25	μs
	6N138			$I_F=12\text{mA}$, $R_L=270\Omega$	—	0.2	1	
				$I_F=1.6\text{mA}$, $R_L=2.2\text{k}\Omega$	—	1	10	
Propagation Delay Time to Logic High at Output (Note 6, 8)	6N138	t_{pLH} (*)	1	$I_F=0.5\text{mA}$, $R_L=4.7\text{k}\Omega$	—	5	60	μs
	6N139			$I_F=12\text{mA}$, $R_L=270\Omega$	—	1	7	
				$I_F=1.6\text{mA}$, $R_L=2.2\text{k}\Omega$	—	4	35	
Common Mode Transient Immunity at Logic High Level Output (Note 9)		CM_H	2	$I_F=0\text{mA}$, $R_L=2.2\text{k}\Omega$ $V_{CM}=400V_{p-p}$	—	500	—	$V / \mu\text{s}$
Common Mode Transient Immunity at Logic Low Level Output (Note 9)		CM_L	2	$I_F=1.6\text{mA}$ $R_L=2.2\text{k}\Omega$ $V_{CM}=400V_{p-p}$	—	−500	—	$V / \mu\text{s}$

(*)JEDEC Registered Data.

(Note 1) Derate linearly above 50°C free-air temperature at a rate of $0.4\text{mA}/^\circ\text{C}$.(Note 2) Derate linearly above 50°C free-air temperature at a rate of $0.7\text{mW}/^\circ\text{C}$.(Note 3) Derate linearly above 25°C free-air temperature at a rate of $0.7\text{mA}/^\circ\text{C}$.(Note 4) Derate linearly above 25°C free-air temperature at a rate of $2.0\text{mW}/^\circ\text{C}$.(Note 5) DC CURRENT TRANSFER RATIO is defined as the ratio of output collector current, I_O , to the forward LED input current, I_F , times 100%.

(Note 6) Pin 7 Open.

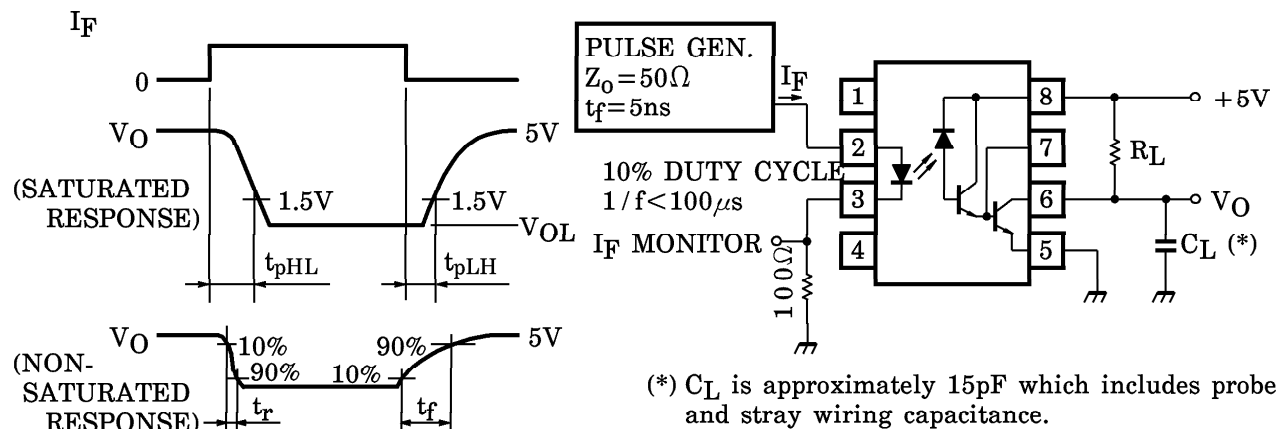
(Note 7) Device considered a two-terminal device : Pins 1, 2, 3, and 4 shorted together and Pins 5, 6, 7, and 8 shorted together.

(Note 8) Use of a resistor between pin 5 and 7 will decrease gain and delay time.

(Note 9) Common mode transient immunity in Logic High level is the maximum tolerable (positive) dv_{CM}/dt on the leading edge of the common mode pulse, V_{CM} , to assure that the output will remain in a Logic High state (i.e., $V_O > 2.0\text{V}$).

Common mode transient immunity in Logic Low level is the maximum tolerable (negative) dv_{CM}/dt on the trailing edge of the common mode pulse signal, V_{CM} , to assure that the output will remain in a Logic Low state (i.e., $V_O < 0.8\text{V}$).

TEST CIRCUIT 1.



TEST CIRCUIT 2.

